

DF005M - DF10M

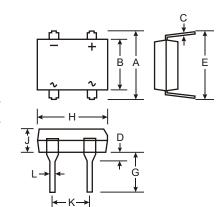
1.0A GLASS PASSIVATED BRIDGE RECTIFIERS

Features

- Glass Passivated Die Construction
- **Diffused Junction**
- Low Forward Voltage Drop, High Current Capability
- Surge Overload Rating to 50A Peak
- Designed for Printed Circuit Board Applications
- UL Listed Under Recognized Component Index, File Number E94661
- Lead Free Finish, RoHS Compliant (Note 3)

Mechanical Data

- Case: DF-M
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Bright Tin. Solder Plated Leads, Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Bright Tin Finish). Please see Ordering Information, Note 5, on Page 3
- Polarity: As Marked on Case
- Marking: Type Number, See Page 3
- Weight: 0.38 grams (approximate)



DF-M						
Dim	Min	Max				
Α	7.40	7.90				
В	6.20	6.50				
С	0.22	0.30				
D	1.27	2.03				
E	7.60	8.90				
G	3.81	4.69				
Н	8.13	8.51				
J	2.40	2.60				
K	5.00	5.20				
L	0.46	0.58				
М	1.40	1.56				
N	2.10	2.34				
All Dimensions in mm						

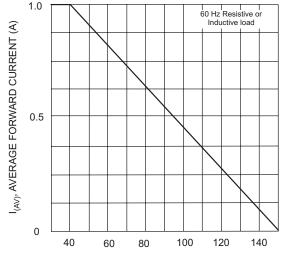
Maximum Ratings and Electrical Characteristics @ $T_A = 25$ °C unless otherwise specified

Single phase, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

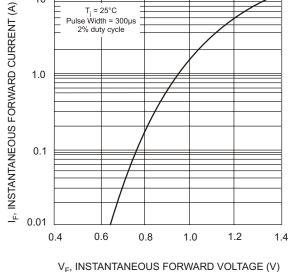
Characteristic	Symbol	DF 005M	DF 01M	DF 02M	DF 04M	DF 06M	DF 08M	DF 10M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RMM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	580	700	V
Average Rectified Output Current @ T _A = 40°C	lo	1.0				Α			
Non-Repetitive Peak Forward Surge Current, 8.3 ms single half-sine-wave superimposed on rated load (JEDEC method)	I _{FSM}				50				А
Forward Voltage (per element) @ I _F = 1.0 A	V _{FM}	1.1			V				
Peak Reverse Current @ T _A = 25°C at Rated DC Blocking Voltage (per element) @ T _A = 125°C	I _{RM}				10 500				μА
I ² t Rating for Fusing (t<8.3ms)		10.4					A ² s		
Typical Total Capacitance per element (Note 1)		25					pF		
Typical Thermal Resistance, Junction to Ambient (Note 2)		40					°C/W		
Operating and Storage Temperature Range		-65 to +150					°C		

- 1. Measured at 1.0MHz and Applied Reverse Voltage of 4.0V DC.
- 2. Thermal Resistance, junction to ambient, measured on PC board with 5.02mm (0.03mm thick) land areas.
- 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.



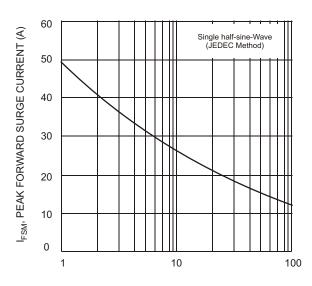


T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Output Current Derating Curve

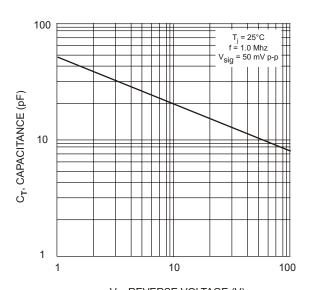


10

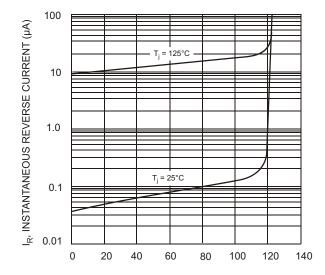
V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current



 $\label{eq:VR} {\rm V_R,\,REVERSE\,\,VOLTAGE\,\,(V)}$ Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typ Reverse Characteristics (per element)



Ordering Information (Notes 4 & 5)

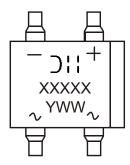
Device*	Packaging	Shipping
DFxM	DF-M	Tube
DFxM-T	DF-M	1500/Tape & Reel, 13-inch

^{*} x = Device type, e.g. DF005S or DF10S, etc.

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

5. For Lead Free/RoHS Compliant version part numbers, please add "-F" suffix to the part numbers above. Example: DF10M-T-F.

Marking Information



Oll = Manufacturers' code marking
XXXXX = Product type marking code, ex: DF10M
YWW = Date code marking
Y = Last digit of year ex: 2 for 2002
WW = Week code 01 to 52